



MMDT5551

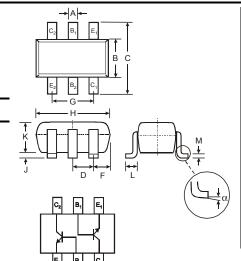
DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMDT5401)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4N, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



| | SOT-363 | | | | | | | | | | |
|---------|----------|--------|--|--|--|--|--|--|--|--|--|
| Dim | Min | Max | | | | | | | | | |
| Α | 0.10 | 0.30 | | | | | | | | | |
| В | 1.15 | 1.35 | | | | | | | | | |
| С | 2.00 | 2.20 | | | | | | | | | |
| D | 0.65 N | ominal | | | | | | | | | |
| F | 0.30 | 0.40 | | | | | | | | | |
| Н | 1.80 | 2.20 | | | | | | | | | |
| J | _ | 0.10 | | | | | | | | | |
| K | 0.90 | 1.00 | | | | | | | | | |
| L | 0.25 | 0.40 | | | | | | | | | |
| М | 0.10 | 0.25 | | | | | | | | | |
| α | 0° | 8° | | | | | | | | | |
| All Din | nensions | in mm | | | | | | | | | |

Maximum Ratings @TA = 25°C unless otherwise specified

| Characteristic | | Symbol | Value | Unit |
|---|-------------|-----------------------------------|-------------|------|
| Collector-Base Voltage | | V _{CBO} | 180 | V |
| Collector-Emitter Voltage | | V_{CEO} | 160 | V |
| Emitter-Base Voltage | | V_{EBO} | 6.0 | V |
| Collector Current - Continuous | (Note 1) | Ic | 200 | mA |
| Power Dissipation | (Note 1, 2) | P_d | 200 | mW |
| Thermal Resistance, Junction to Ambient | (Note 1) | $R_{	hetaJA}$ | 625 | °C/W |
| Operating and Storage Temperature Range | | T _j , T _{STG} | -55 to +150 | °C |

Notes:

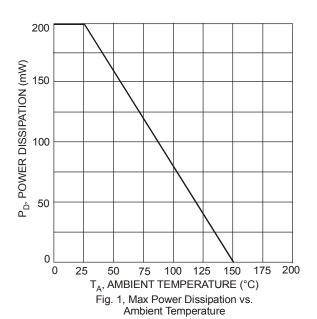
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. Maximum combined dissipation.
- 3. No purposefully added lead.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

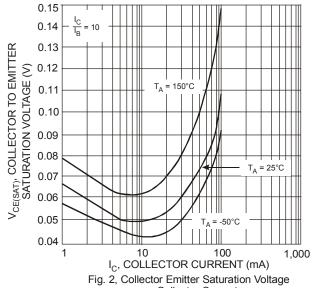


Electrical Characteristics @T_A = 25°C unless otherwise specified

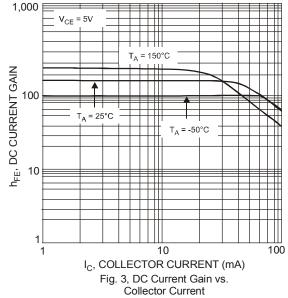
| Characteristic | Symbol | Min | Max | Unit | Test Condition |
|--------------------------------------|----------------------|----------------|--------------|----------|--|
| OFF CHARACTERISTICS (Note 6) | · | | | | |
| Collector-Base Breakdown Voltage | V _{(BR)CBO} | 180 | _ | V | $I_C = 100 \mu A, I_E = 0$ |
| Collector-Emitter Breakdown Voltage | V _{(BR)CEO} | 160 | _ | V | $I_C = 1.0 \text{mA}, I_B = 0$ |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | 6.0 | _ | V | $I_E = 10 \mu A, I_C = 0$ |
| Collector Cutoff Current | Ісво | _ | 50 | nA μA | V _{CB} = 120V, I _E = 0 V _{CB} = 120V, I _E = 0, T _A = 100°C |
| Emitter Cutoff Current | I _{EBO} | _ | 50 | nA | $V_{EB} = 4.0V, I_{C} = 0$ |
| ON CHARACTERISTICS (Note 6) | · | | | | |
| DC Current Gain | h _{FE} | 80 80 30 | 250 — | _ | I_C = 1.0mA, V_{CE} = 5.0V I_C = 10mA, V_{CE} = 5.0V I_C = 50mA, V_{CE} = 5.0V |
| Collector-Emitter Saturation Voltage | V _{CE(SAT)} | _ | 0.15 0.20 | V | I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA |
| Base-Emitter Saturation Voltage | | _ | 1.0 | V | I _C = 10mA, I _B = 1.0mA I _C = 50mA, I _B = 5.0mA |
| SMALL SIGNAL CHARACTERISTICS | · | | | | |
| Output Capacitance | C_{obo} | _ | 6.0 | pF | V _{CB} = 10V, f = 1.0MHz, I _E = 0 |
| Small Signal Current Gain | h _{fe} | 50 | 250 | | V _{CE} = 10V, I _C = 1.0mA, f = 1.0kHz |
| Current Gain-Bandwidth Product | f _T | 100 | 300 | MHz | V _{CE} = 10V, I _C = 10mA, f = 100MHz |
| Noise Figure | NF | _ | 8.0 | dB | V_{CE} = 5.0V, I_{C} = 200 μ A, R_{S} = 1.0k Ω , f = 1.0kHz |

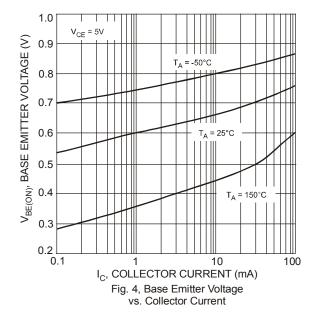
Notes: 6. Short duration pulse test used to minimize self-heating effect.

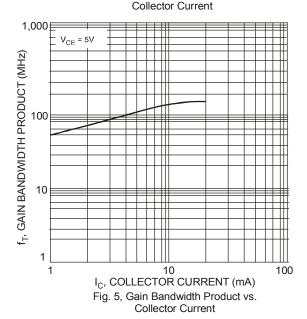










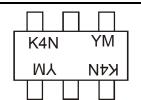


Ordering Information (Note 7)

| ĺ | Device | Packaging | Shipping | | |
|---|--------------|-----------|------------------|--|--|
| | MMDT5551-7-F | SOT-363 | 3000/Tape & Reel | | |

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K4N = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

| Date Code Ney | | | | | | | | | | | | | | | |
|---------------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
| Code | J | K | L | М | Ν | Р | R | S | Т | U | V | W | X | Υ | Z |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

Downloaded From Oneyac.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达尔科技)